NSN 5961-00-172-7870

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-172-7870 **Inclosure Material:** Glass and metal **Overall Length:** Between 0.272 inches and 0.292 inches **Terminal Length:** 0.600 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud Features Provided: Hermetically sealed case **Overall Width Across Flats:** 0.187 inches **Thread Size:** 0.112 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1000.0 reverse voltage, peak **Current Rating Per Characteristic:** 10.00 microamperes reverse current, dc **Power Rating Per Characteristic:** 15.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Thread Series Designator:** Unc **Terminal Type And Quantity:** 2 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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